NSN 5961-01-466-1430

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-466-1430 **Inclosure Material:** Glass **Overall Length:** 4.250 millimeters **Terminal Length:** 2.600 millimeters **Overall Width:** 4.600 millimeters **End Application:** 6625-01-443-0552 **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 45.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Low frequency low power silicon pnp bjt **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No